

TOF SIMS Temperature Study of Hydrogen in Niobium

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INTRODUCTION

- Previous work has shown that H content in Nb can be related to the efficiency of SRF cavities.¹
- A heat treated (800°C : 3hrs; 120°C : 24hrs) large grain Nb sample shows less H near surface and higher RRR compared with a non heat treated sample.

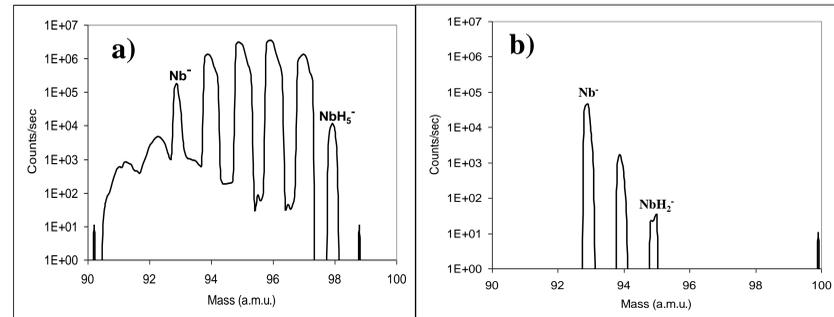


Fig.1 SIMS Mass spectra of Nb large grain samples. a) non heat treated, b) heat treated. Significant reduction in H containing species due to heat treatment²

• All TOF-SIMS analyses were made using a 25keV Bi₃⁺ analysis beam and a 10keV Cs⁺ sputter beam.

• The sputter area was 120x120 μm² and the detected area was 50x50 μm² with analysis current of 0.7pA and sputter current of 20nA

LOW TEMPERATURE ANALYSES

• Analyses were performed first decreasing temperature from 300 to 160°K and then increasing to 300°K.

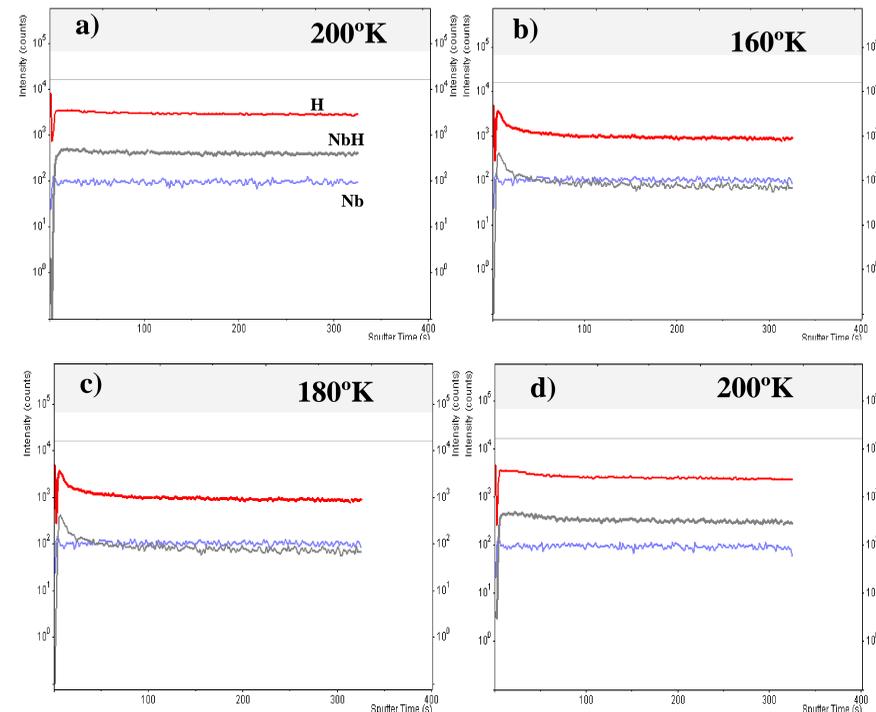
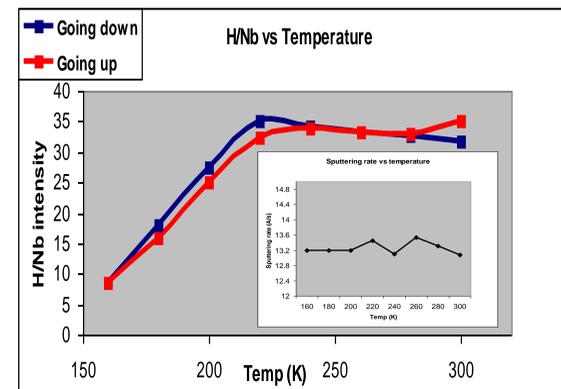


Fig.2 H signal vs time as temperature is decreased from 200-160°K (Fig. 2 a and b) and increased from 180-200°K (Fig. 2 c and d). Results indicate that H signal decreases as temperature reduced below 200°K

Fig. 3 H/Nb ratios obtained in the temperature range 160-300°K. The difference in the two curves shows thermal hysteresis. H seems to follow a trend of first increasing and then decreasing as temp is decreased. This effect was reproducible. Enclosed fig. shows sputtering rate vs temperature



HIGH TEMPERATURE ANALYSES

• TOF SIMS was also used for high temperature analyses (300-475°K) on a control sample.

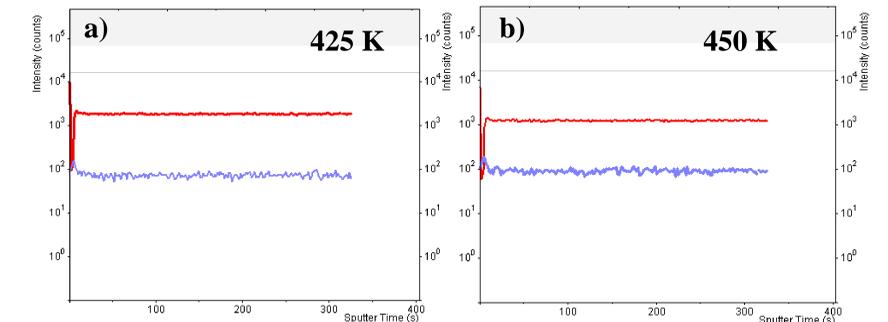
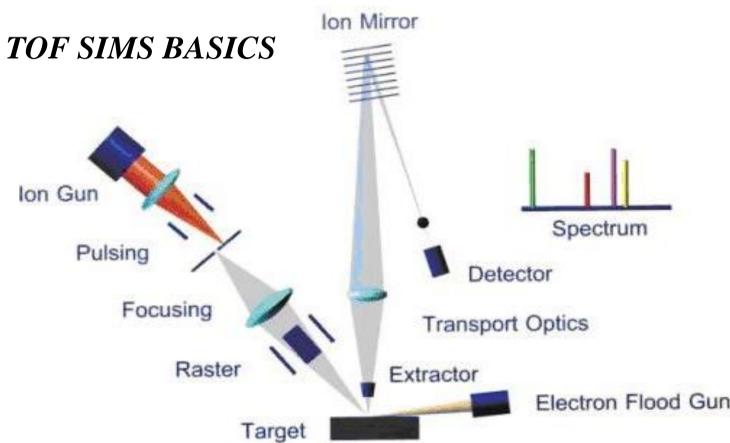


Fig. 4 H signal vs time data shows a significant decrease in H/Nb intensity as specimen is heated from 425 to 450°K

TOF SIMS BASICS



OBJECTIVE

To study the behavior of H in Nb at low temperatures (160 - 300°K) and high temperatures (300-475°K).

SAMPLES & INSTRUMENTATION

- Large grain Nb non heat treated (control) samples were used for both the high and low temperature studies.
- ION-TOF 5 Time of Flight Secondary Ion Mass Spectrometer (TOF-SIMS) with a cold/hot stage was used to study the top 200nm surface of the specimens for H levels.

CONCLUSION

- TOF SIMS analyses of H in Nb were performed both at low and elevated temperatures.
- Low temperature analyses showed that H/Nb intensity decreased significantly for T < 200°K and that it reaches a maximum for 200 > T > 250°K. H/Nb intensity also seems to decrease at T > 425°K in the elevated temp analyses.
- Future work is planned to study the phase transformations of H in Nb using Differential Scanning Calorimetry and X-Ray Diffraction techniques and correlate this data to the H-Nb phase diagram.

REFERENCES

1. G. Ciovati, G. Myneni, F. Stevie, P. Maheshwari, D. Griffis, *Physical Review Special Topics-Accelerators and Beams* 13, 022002 (2010)
2. P. Maheshwari, et al., *Surf. Int. Anal.* 43, 153 (2011)